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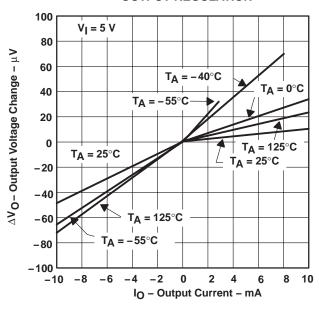
- 2.5-V Virtual Ground for 5-V/GND Analog Systems
- High Output-Current Capability Sink or Source . . . 20 mA Typ
- Micropower Operation . . . 170 μA Typ
- Excellent Regulation Characteristics
 - Output Regulation
 - $-45 \mu V$ Typ at $I_O = 0$ to -10 mA
 - +15 μ V Typ at I_O = 0 to +10 mA
 - Input Regulation = 1.5 μV/V Typ
- Low-Impedance Output . . . 0.0075 Ω Typ
- Macromodel Included

description

In signal-conditioning applications using a single power source, a reference voltage is required for termination of all signal grounds. To accomplish this, engineers have typically used solutions consisting of resistors, capacitors, operational amplifiers, and voltage references. Texas Instruments has eliminated all of those components with one easy-to-use 3-terminal device. That device is the TLE2425 precision virtual ground.

Use of the TLE2425 over other typical circuit solutions gives the designer increased dynamic signal range, improved signal-to-noise ratio, lower distortion, improved signal accuracy, and easier interfacing to ADCs and DACs. These benefits are the result of combining a precision micropower voltage reference and a high-performance precision operational amplifier in a single silicon chip. It is the precision and performance of these two circuit functions together that yield such dramatic system-level performance.

OUTPUT REGULATION



The TLE2425 improves input regulation as well as output regulation and, in addition, reduces output impedance and power dissipation in a majority of virtual-ground-generation circuits. Both input regulation and load regulation exceed 12 bits of accuracy on a single 5-V system. Signal-conditioning front ends of data acquisition systems that push 12 bits and beyond can use the TLE2425 to eliminate a major source of system error.

AVAILABLE OPTIONS

TA	SMALL OUTLINE (D)	PLASTIC TO-226AA (LP)
0°C to 70°C	TLE2425CD	TLE2425CD
-40°C to 85°C	TLE2425ID	TLE2425ID
-55°C to 125°C	TLE2425MD	_

[†] The D package is available taped and reeled. Add R suffix to the device type (e.g., TLE2425CDR).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



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D, OR JG PACKAGE LP PACKAGE (TOP VIEW) (TOP VIEW) OUT 8 NC IN COMMON 7 NC COMMON 6 NC IN 3 OUT NC I NC

NC - No internal connection

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Output current, IO		
·	, , , , , , , , , , , , , , , , , , , ,	unlimited
		See Dissipation Rating Table
Operating free-air temperature range, T _A :	C-suffix	0°C to 70°C
	I-suffix	–40°C to 85°C
	M-suffix	–55°C to 125°C
Storage temperature range, T _{stq}		–65°C to 150°C
) package 260°C
Lead temperature 1,6 mm (1/16 inch) from	n case for 60 seconds: J	G or LP package 300°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{A}} \le 25^{\circ}\mbox{C}$ POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING	T _A = 125°C POWER RATING
D	725 mV	5.8 mW/°C	464 mW	377 mW	145 mW
JG	1050 mV	8.4 mW/°C	672 mW	546 mW	210 mW
LP	775 mV	6.2 mW/°C	496 mW	403 mW	155 mW

recommended operating conditions

	C-SUFFIX		I-SUFFIX		M-SU		
	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
Input voltage, V _I	4	40	4	40	4	40	V
Operating free-air temperature, T _A	0	70	-40	85	-55	125	°C

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electrical characteristics at specified free-air temperature, V_{I} = 5 V, I_{O} = 0 (unless otherwise noted)

DADAMETED	TEST COL	IDITIONS	- t	TL	E24250	;	LINUT	
PARAMETER	TEST CON	IDITIONS	T _A †	MIN	TYP	MAX	UNIT	
Output walkana			25°C	2.48	2.5	2.52	V	
Output voltage			Full range	2.47		2.53	V	
Temperature coefficient of output voltage			25°C		20		ppm/°C	
Diagram and			25°C		170	250		
Bias current	IO = 0		Full range			250	μΑ	
	V 45V 55V		25°C		1.5	20	/	
Land on the second of the	$V_{I} = 4.5 \text{ V to } 5.5 \text{ V}$	Full range			25	μV		
Input voltage regulation	V 4.V to 40.V		25°C		1.5	20	////	
	V _I = 4 V to 40 V	Full range			25	μV/V		
Ripple rejection	f = 120 Hz,	$\Delta V_{I(PP)} = 1 V$	25°C		80		dB	
	L 04: 40 mA		25°C	-160	-45	160		
Output voltage regulation (source current)‡	$I_{O} = 0 \text{ to } -10 \text{ mA}$		Full range	-250		250	μV	
	$I_0 = 0 \text{ to } -20 \text{ mA}$	25°C	-450	-150	450			
	lo = 0 to 10 mA		25°C	-160	15	160		
Output voltage regulation (sink current)‡	$I_O = 0 \text{ to } 10 \text{ mA}$	Full range	-250		250	μV		
	$I_O = 0$ to 20 mA	25°C	-235	65	235			
Long-term drift of output voltage	$\Delta t = 1000 \text{ h},$	Noncumulative	25°C		15		ppm	
Output impedance			25°C		7.5	22.5	mΩ	
Short-circuit output current (sink current)	V _O = 5 V		25°C	30	55		A	
Short-circuit output current (source current)	V _O = 0		25°C	-30	-50		mA	
Output noise voltage, rms	f = 10 Hz to 10 kHz		25°C		100		μV	
	V _O to 0.1%,	C _L = 0			110			
Output valtage seemand to output ourself atom	$I_O = \pm 10 \text{ mA}$	C _L = 100 pF	0500		115			
Output voltage response to output current step	V _O to 0.01%,	C _L = 0	25°C		180		μs	
	$I_O = \pm 10 \text{ mA}$	C _L = 100 pF			180			
Outside the second of the second of	V _I = 4.5 to 5.5 V, V _O to 0.1%		$V_{\rm I} = 4.5 \text{ to } 5.5 \text{ V}, V_{\rm O} \text{ to } 0.1\%$				_	
Output voltage response to input voltage step	$V_I = 4.5 \text{ to } 5.5 \text{ V},$	V _O to 0.01%	25°C		30		μs	
Output valta na tuma an mana	$V_{I} = 0 \text{ to } 5 \text{ V},$	V _O to 0.1%	0500		125		μs	
Output voltage turn-on response	$V_{I} = 0 \text{ to } 5 \text{ V},$	V _O to 0.01%	25°C		210	210		

[†] Full range is 0°C to 70°C. ‡ The listed values are not production tested.

TLE2425 PRECISION VIRTUAL GROUND

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electrical characteristics at specified free-air temperature, V_{I} = 5 V, I_{O} = 0 (unless otherwise noted)

DADAMETER		NDITIONS.	- +	Т	LE2425I		
PARAMETER	TEST CO	NDITIONS	T _A †	MIN	TYP	MAX	UNIT
0			25°C	2.48	2.5	2.52	.,
Output voltage		Full range	2.47		2.53	V	
Temperature coefficient of output voltage			25°C		20		ppm/°C
D		25°C		170	250		
Bias current	IO = 0		Full range			250	μΑ
	V 45V1255V		25°C		1.5	20	.,
	$V_1 = 4.5 \text{ V to } 5.5 \text{ V}$	Full range			75	μV	
Input voltage regulation	., .,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,				1.5	20	
	$V_I = 4 \text{ V to } 40 \text{ V}$	Full range			75	μV/V	
Ripple rejection	f = 120 Hz,	$\Delta V_{I(PP)} = 1 V$	25°C		80		dB
	ĺ ,		25°C	-160	-45	160	
Output voltage regulation (source current)‡	$I_{O} = 0 \text{ to } -10 \text{ mA}$		Full range	-250		250	μV
	$I_{O} = 0 \text{ to } -20 \text{ mA}$		25°C	-450	-150	450	
		25°C	-160	15	160		
output voltage regulation (sink current)‡	$I_O = 0 \text{ to } 8 \text{ mA}$		Full range	-250		250	μV
	I _O = 0 to 20 mA	25°C	-235	65	235		
Long-term drift of output voltage	$\Delta t = 1000 \text{ h},$	Noncumulative	25°C		15		ppm
Output impedance			25°C		7.5	22.5	mΩ
Short-circuit output current (sink current)	V _O = 5 V		0500	30	55		^
Short-circuit output current (source current)	VO = 0		25°C	-30	-50		mA
Output noise voltage, rms	f = 10 Hz to 10 kHz	Z	25°C		100		μV
	V _O to 0.1%,	C _L = 0			110		
Output valte as a second of subset or second of	$I_O = \pm 10 \text{ mA}$	C _L = 100 pF	0500		115		
Output voltage response to output current step	V _O to 0.01%,	C _L = 0	25°C		180		μs
	$I_{O} = \pm 10 \text{ mA}$ $C_{L} = 100 \text{ pF}$				180		
Output valtage reasons to imput valtage at	V _I = 4.5 to 5.5 V, V _O to 0.1%		2500		12		μs
Output voltage response to input voltage step	$V_I = 4.5 \text{ to } 5.5 \text{ V},$	V _O to 0.01%	25°C		30		
Output valtage to the	$V_{I} = 0 \text{ to } 5 \text{ V},$	V _O to 0.1%	2500		125		
Output voltage turn-on response	$V_{I} = 0 \text{ to } 5 \text{ V},$	V _O to 0.01%	25°C		210		μѕ

[†] Full range is –40°C to 85°C.

[‡]The listed values are not production tested.

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electrical characteristics at specified free-air temperature, V_{I} = 5 V, I_{O} = 0 (unless otherwise noted)

DADAMETED	TEST COL	IDITIONS	- t	TL	E2425N	1		
PARAMETER	TEST CON	NDITIONS	T _A †	MIN	TYP	MAX	UNIT	
Output walkana			25°C	2.48	2.5	2.52	V	
Output voltage			Full range	2.47		2.53	V	
Temperature coefficient of output voltage			25°C		20		ppm/°C	
Discount			25°C		170	250		
Bias current	IO = 0		Full range			250	μΑ	
	V 45V4 55V		25°C		1.5	20		
land valtage regulation	$V_{I} = 4.5 \text{ V to } 5.5 \text{ V}$	Full range			100	μV		
Input voltage regulation	V: 45 V/+= 40 V/		25°C		1.5	20	\//\/	
	$V_{I} = 4.5 \text{ V to } 40 \text{ V}$	Full range			100	μV/V		
Ripple rejection	f = 120 Hz,	$\Delta V_{I(PP)} = 1 V$	25°C		80		dB	
	1 045 40 554		25°C	-160	-45	160		
Output voltage regulation (source current)‡	$I_{O} = 0 \text{ to } -10 \text{ mA}$		Full range	-250		250	μV	
	$I_0 = 0 \text{ to } -20 \text{ mA}$		25°C	-450	-150	450		
	lo = 0 to 2 mA		25°C	-160	15	160		
Output voltage regulation (sink current)‡	$I_O = 0$ to 3 mA	Full range	-250		250	μV		
	$I_O = 0$ to 20 mA	25°C	-235	65	235			
Long-term drift of output voltage	$\Delta t = 1000 \text{ h},$	Noncumulative	25°C		15		ppm	
Output impedance			25°C		7.5	22.5	mΩ	
Short-circuit output current (sink current)	V _O = 5 V		25°C	30	55		A	
Short-circuit output current (source current)	V _O = 0		25°C	-30	-50		mA	
Output noise voltage, rms	f = 10 Hz to 10 kHz		25°C		100		μV	
	V _O to 0.1%,	C _L = 0			110			
Output valta as assessed to sutput ourset atom	$I_O = \pm 10 \text{ mA}$	$C_L = 100 pF$	0500		115			
Output voltage response to output current step	V _O to 0.01%,	C _L = 0	25°C		180		μs	
	$I_O = \pm 10 \text{ mA}$	$C_L = 100 pF$			180			
Outrout valta na nasa sa ta innut valta na atan	$V_1 = 4.5 \text{ to } 5.5 \text{ V},$	V _O to 0.1%	2500		12			
Output voltage response to input voltage step	$V_1 = 4.5 \text{ to } 5.5 \text{ V},$	V _O to 0.01%	25°C		30		μs	
Output voltage turn on response	$V_{I} = 0 \text{ to } 5 \text{ V},$	V _O to 0.1%	25°C		125			
Output voltage turn-on response	$V_{I} = 0 \text{ to } 5 \text{ V},$	V _O to 0.01%	20 0	210			μs	

[†] Full range is –55°C to 125°C. ‡ The listed values are not production tested.

TYPICAL CHARACTERISTICS

Table Of Graphs

		FIGURE
Output valtage	Distribution	1
Output voltage	vs Free-air temperature	2
Output voltage hysteresis	vs Free-air temperature	3
Land bin a summer	vs Input voltage	4
Input bias current	vs Free-air temperature	5
Input voltage regulation		6
Ripple rejection	vs Frequency	7
Output voltage regulation		8
Output impedance	vs Frequency	9
Short-circuit output current	vs Free-air temperature	10
Spectral noise voltage density	vs Frequency	11
Wide-band noise voltage	vs Frequency	12
Output voltage change with current step	vs Time	13
Output voltage change with voltage step	vs Time	14
Output voltage power-up response	vs Time	15
Output current	vs Load capacitance	16

OUTPUT VOLTAGE

TYPICAL CHARACTERISTICS[†]

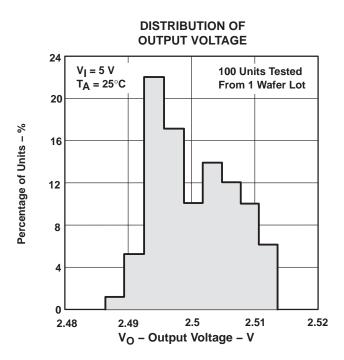


Figure 1

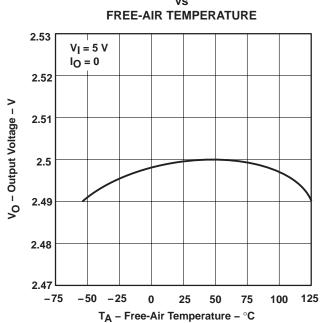
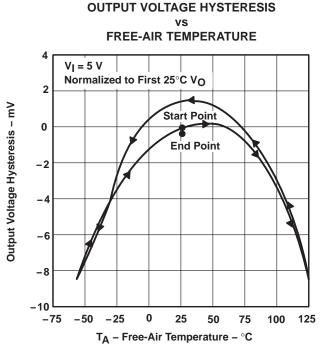
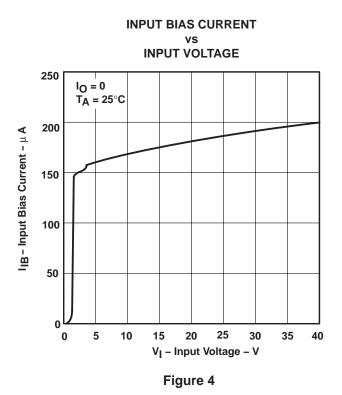


Figure 2







† Data at high and low temperatures are applicable within rated operating free-air temperature ranges of the various devices.



TYPICAL CHARACTERISTICS[†]

INPUT BIAS CURRENT vs FREE-AIR TEMPERATURE

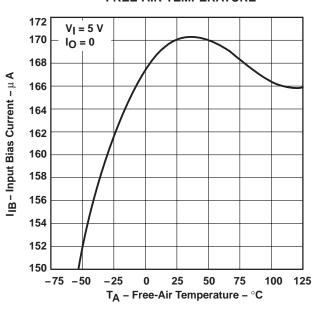


Figure 5

Figure 6



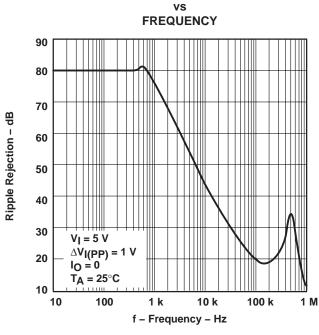


Figure 7

OUTPUT VOLTAGE REGULATION

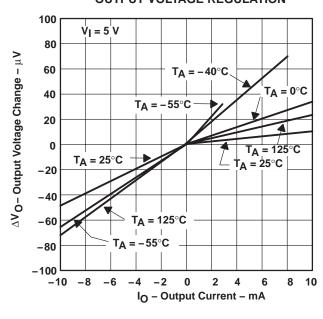


Figure 8

[†]Data at high and low temperatures are applicable within rated operating free-air temperature ranges of the various devices.



TYPICAL CHARACTERISTICS

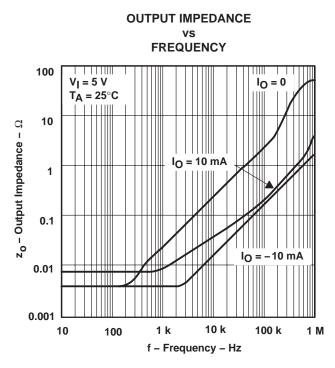
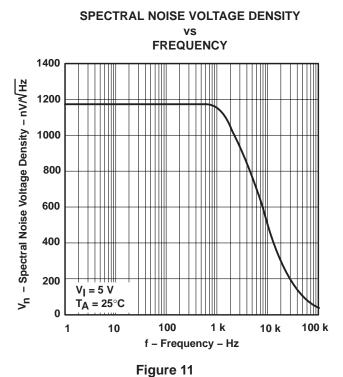


Figure 9



SHORT-CIRCUIT OUTPUT CURRENT
vs
FREF-AIR TEMPERATURE

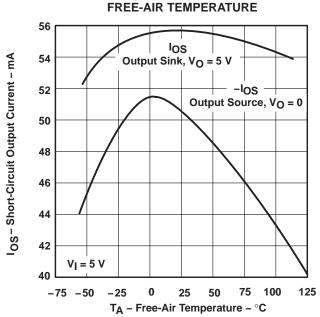


Figure 10

WIDE-BAND NOISE VOLTAGE vs

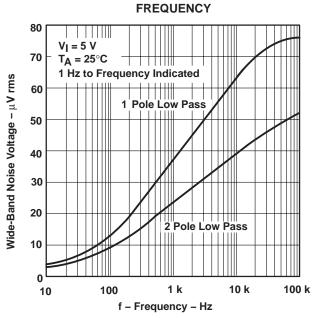


Figure 12

TYPICAL CHARACTERISTICS

OUTPUT VOLTAGE RESPONSE TO OUTPUT CURRENT STEP vs TIME 1.5 V ∆Vo - Change In Output Voltage - mV V_I = 5 V 3 $C_L = 100 pF$ $T_A = 25^{\circ}C$ 0.1% 2 0.01% **VO** Response 0.01% -2 10 mA 0.1% IO Step -3 0 -4 -10 mA -1.5 V 0 1050 150 300 450 600 750 900 t - Time - μs

Figure 13

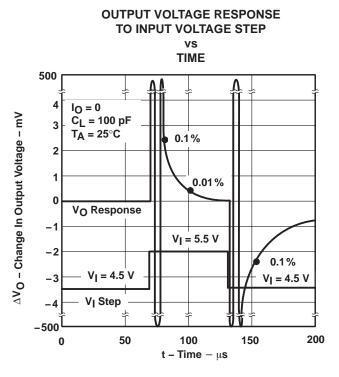


Figure 14

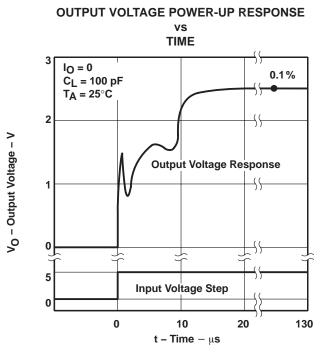


Figure 15

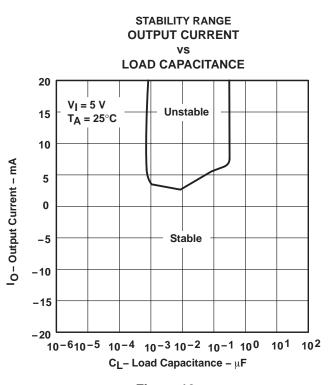


Figure 16

macromodel information

```
* TLE2425 OPERATIONAL AMPLIFIER "MACROMODEL" SUBCIRCUIT
* CREATED USING PARTS RELEASE 4.03 ON 08/21/90 AT 13:51
* REV (N/A) SUPPLY VOLTAGE: 5 V
* CONNECTIONS: INPUT
* | COMMON
* | OUTPUT
* | .
SUBCKT TLE2425 3 4 5
```

```
OPAMP SECTION
C1
      11 12 21.66E-12
C2
        6 7
             30.00E-12
       87 0 10.64E-9
C3
CPSR
       85 86 15.9E-9
      81 82 DX
DCM+
DCM-
       83 81 DX
       5 53 DX
DC
DE
       54 5
             DX
DLN
       92 90 DX
DLP
      90 91 DX
DP
       4 3
             DX
      84 99 (2,99) 1
ECMR
                       (3,0) (4,0) 0 .5 .5
(3,4) -16.22E-6 3.24E-6
(88,0) 120E-6 1
EGND
      99 0
             POLY(2)
EPSR
       85 0
             POLY(1)
ENSE
       89 2
             POLY(1)
FΒ
       7 99 POLY(6)
                        VB VC VE VLPVLNVPSR O 74.8E6 -10E6 10E6
                                                                       10E6
-10E6 74E6
GΑ
        6 0
             11 12 320.4E-6
GCM
        0 6
             10 99 1.013E-9
GPSR
      85 86 (85,86)
                       100E-6
GRC1
       4
          11
              (4,11) 3.204E-4
             (4,12) 3.204E-4
GRC2
       4
          12
GRE1
       13 10 (13,10)
                       1.038E-3
GRE2
       14 10 (14,10)
                       1.038E-3
             VLIM 1K
       90 0
HLIM
HCMR
       80 1
             POLY(2)
                        VCM+ VCM-
                                     0 1E2 1E2
TRP
             146E-6
       3 4
       3 10 DC 24.05E-6
IEE
             .2E-9
IIO
       2 0
       88 0
             1E-21
I1
Q1
       11 89 13 QX
Q2
       12 80 14 QX
R2
       6 9
             100.0E3
       84 81 1K
RCM
REE
      10 99 8.316E6
RN1
       87 0
             2.55E8
RN2
      87 88 11.67E3
```

TLE2425 PRECISION VIRTUAL GROUND

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macromodel information (continued)

```
8 5
          7 99 62
   RO2
   VCM+
          82 99 1.0
   VCM-
          83 99 -2.3
   VB
          9 0 DC 0
   VC
          3 53 DC
                    1.400
          54 4 DC 1.400
   VE
   VLIM
          7 8 DC 0
          91 0 DC 30
0 92 DC 30
   VLP
   VLN
   VPSR
          0 86 DC 0
   RFB
          5 2
                1K
          30 1 1K
   RIN
   RCOM
         34 4
                .1
*REGULATOR SECTION
         30 0 20MEG
30 31 .2
   RG1
   RG2
          31 35 400K
   RG3
         35 34 411K
31 36 25MEG
   RG4
   RG5
                         VPSET VNSET 0 1E2 1E2
   HREG
         31 32 POLY(2)
   VREG
         32 33 DC 0V
                           (36,34)
   EREG
         33 34 POLY(1)
                                     1.23 1
   VADJ
         36 34 1.27V
   HPSET 37 0 VREG
VPSET 38 0 DC 20
                       1.030E3
                DC 20V
   HNSET 39 0 VREG 6.11E5
   VNSET 40 0 DC -20V
   DSUB
          4 34 DX
         37 38 DX
   DPOS
   DNNEG 40 39 DX
.MODEL DX D(IS=800.0E-18)
.MODEL QX PNP(IS=800.0E-18 BF=480)
.ENDS
```







11-Oct-2007

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan ⁽²⁾	Lead/Ball Finis	h MSL Peak Temp ⁽³⁾
5962-9555601Q2A	OBSOLETE	LCCC	FK	20		TBD	Call TI	Call TI
5962-9555601QPA	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI
TLE2425CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2425CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2425CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2425CDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2425CLP	ACTIVE	TO-92	LP	3	1000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type
TLE2425CLPE3	ACTIVE	TO-92	LP	3	1000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type
TLE2425CLPR	OBSOLETE	TO-92	LP	3		TBD	Call TI	Call TI
TLE2425CPS	ACTIVE	SO	PS	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2425CPSG4	ACTIVE	SO	PS	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2425CPSR	ACTIVE	so	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2425CPSRG4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2425ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2425IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2425IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2425IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2425ILP	ACTIVE	TO-92	LP	3	1000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type
TLE2425ILPE3	ACTIVE	TO-92	LP	3	1000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type
TLE2425MD	ACTIVE	SOIC	D	8	75	TBD	CU NIPDAU	Level-1-220C-UNLIM
TLE2425MDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2425MDR	ACTIVE	SOIC	D	8	2500	TBD	CU NIPDAU	Level-1-220C-UNLIM
TLE2425MDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLE2425MFKB	OBSOLETE	LCCC	FK	20		TBD	Call TI	Call TI
TLE2425MJG	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI
TLE2425MJGB	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI
TLE2425MLP	OBSOLETE	TO-92	LP	3		TBD	Call TI	Call TI

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.



PACKAGE OPTION ADDENDUM

11-Oct-2007

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

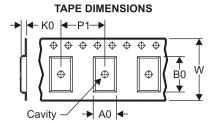
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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLE2425CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2425IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1





*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLE2425CDR	SOIC	D	8	2500	346.0	346.0	29.0
TLE2425IDR	SOIC	D	8	2500	346.0	346.0	29.0

FK (S-CQCC-N**)

28 TERMINAL SHOWN

LEADLESS CERAMIC CHIP CARRIER



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. The terminals are gold plated.
- E. Falls within JEDEC MS-004



D (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AA.





NOTES: A. All linear dimensions are in millimeters.

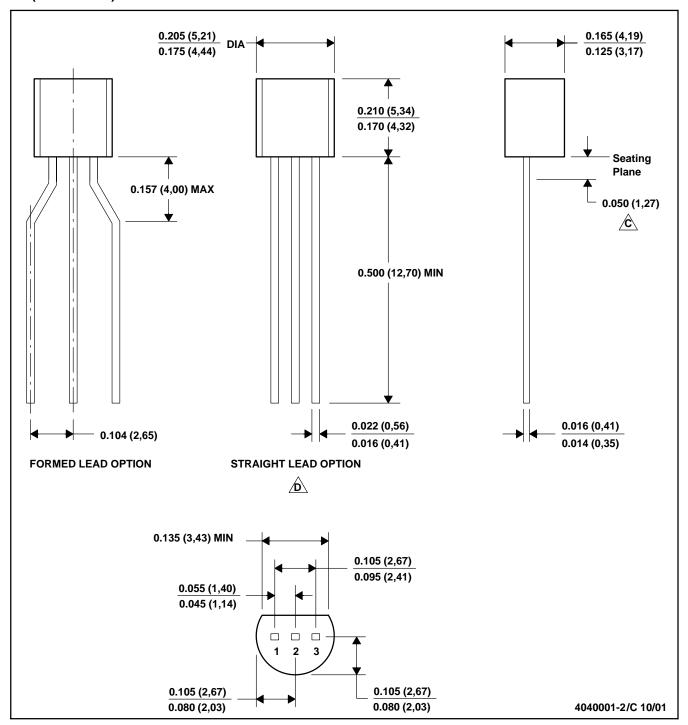
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



LP (O-PBCY-W3)

PLASTIC CYLINDRICAL PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice. $\hfill \hfill \$

C.\ Lead dimensions are not controlled within this area

D. FAlls within JEDEC TO -226 Variation AA (TO-226 replaces TO-92)

E. Shipping Method:

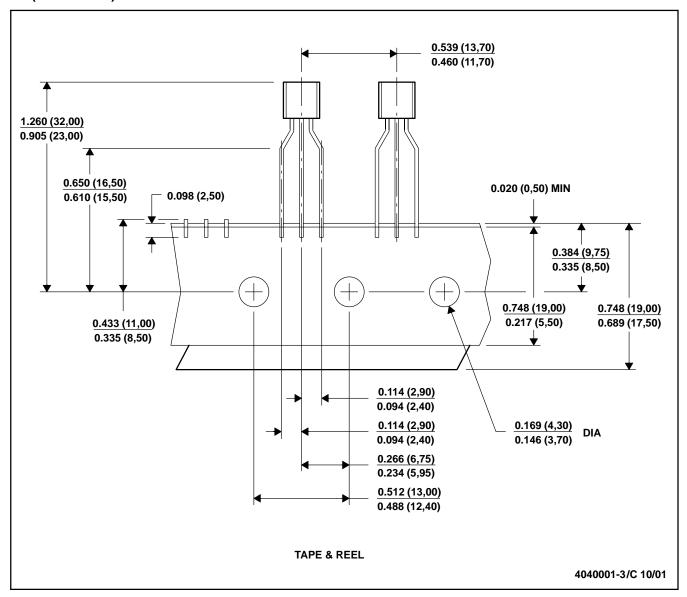
Straight lead option available in bulk pack only.

Formed lead option available in tape & reel or ammo pack.



LP (O-PBCY-W3)

PLASTIC CYLINDRICAL PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Tape and Reel information for the Format Lead Option package.

JG (R-GDIP-T8)

CERAMIC DUAL-IN-LINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
- E. Falls within MIL STD 1835 GDIP1-T8

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